

MOSFETs Silicon N-Channel MOS (π -MOSIV)

TK1Q90A

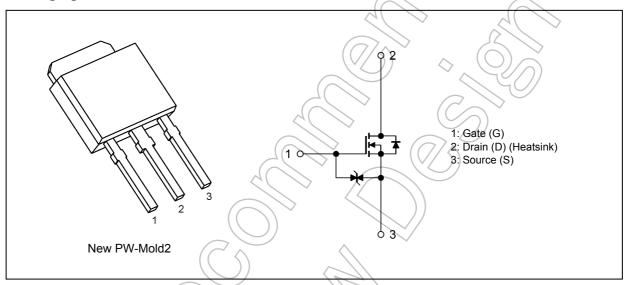
1. Applications

• Switching Voltage Regulators

2. Features

- (1) Low drain-source on-resistance: $R_{DS(ON)} = 6.7 \Omega$ (typ.)
- (2) High forward transfer admittance: $|Y_{fs}| = 1.0 \text{ S (typ.)}$
- (3) Low leakage current: I_{DSS} = 100 μA (max) (V_{DS} = 720 V)
- (4) Enhancement mode: V_{th} = 2.0 to 4.0 V (V_{DS} = 10 V, I_{D} = 1 mA)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) (Ta = 25°C unless otherwise specified)

Characteristics	/ 5)	Symbol	Rating	Unit
Drain-source voltage	V_{DSS}	900	V	
Gate-source voltage	>	V_{GSS}	±30	
Drain current (DC)	(Note 1)	I _D	1	Α
Drain current (pulsed)	(Note 1)	I _{DP}	3	
Power dissipation (T _c = 25°C)		P _D	20	W
Single-pulse avalanche energy	(Note 2)	E _{AS}	216	mJ
Avalanche current		I _{AR}	1	Α
Repetitive avalanche energy	(Note 3)	E _{AR}	2.0	mJ
Channel temperature		T _{ch}	150	°C
Storage temperature		T _{stg}	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production



5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance		6.25	°C/W
Channel-to-ambient thermal resistance	R _{th(ch-a)}	125	

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 396 mH, R_G = 25 Ω , I_{AR} = 1 A

Note 3: Repetitive rating; pulse width limited by maximum channel temperature

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.



6. Electrical Characteristics

6.1. Static Characteristics (T_a = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±10	μΑ
Drain cut-off current	I _{DSS}	V _{DS} = 720 V, V _{GS} = 0 V	7	_	100	
Gate-source breakdown voltage	V _{(BR)GSS}	$I_{G} = \pm 10 \ \mu A, \ V_{DS} = 0 \ V$	±30		_	V
Drain-source breakdown voltage	V _{(BR)DSS}	I _D = 10 mA, V _{GS} = 0 V	900) >	_	
Gate threshold voltage	V_{th}	V _{DS} = 10 V, I _D = 1 mA	2.0	<i>7</i> _	4.0	
Drain-source on-resistance	R _{DS(ON)}	V _{GS} = 10 V, I _D = 0.5 A	/	6.7	9.0	Ω
Forward transfer admittance	Y _{fs}	V _{DS} = 10 V, I _D = 0.5 A	0.3	1.0	_	S

6.2. Dynamic Characteristics (T_a = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	- /	320		pF
Reverse transfer capacitance	C _{rss}	((// \) \^	_((10	_	
Output capacitance	C _{oss}		K	35) —	
Switching time (rise time)	t _r	See Figure 6.2.1.		25		ns
Switching time (turn-on time)	t _{on}			60		
Switching time (fall time)	t _f		//-//	30		
Switching time (turn-off time)	t _{off}	$\langle \rangle \langle \rangle$	\wedge $$	155	_	

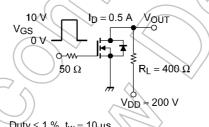


Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics (T_a = 25°C unless otherwise specified)

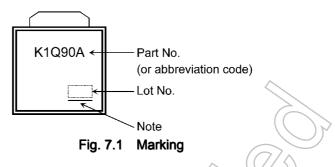
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	$V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 1 \text{ A}$	_	13		nC
Gate-source charge	Q _{gs}		_	6	_	
Gate-drain charge	Q_{gd}		_	7	_	

6.4. Source-Drain Characteristics (T_a = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (DC) (Note 1)	I _{DR}	_	_	_	1	Α
Reverse drain current (pulsed) (Note 1)	I _{DRP}	_	_	_	3	
Diode forward voltage	V _{DSF}	I _{DR} = 1 A, V _{GS} = 0 V	_	_	-1.7	V
Reverse recovery time	t _{rr}	I _{DR} = 1 A, V _{GS} = 0 V	_	550	_	ns
Reverse recovery charge	Q _{rr}	-dI _{DR} /dt = 100 A/μs	_	2.2	_	μС



7. Marking (Note)



Note: A line under a Lot No. identifies the indication of product Labels.

Not underlined: [[Pb]]/INCLUDES > MCV

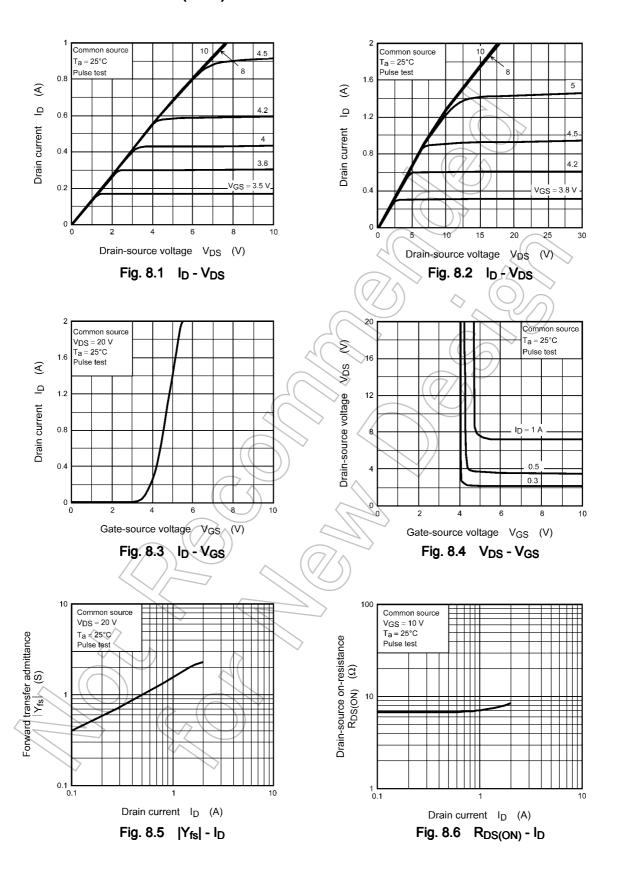
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.



8. Characteristics Curves (Note)



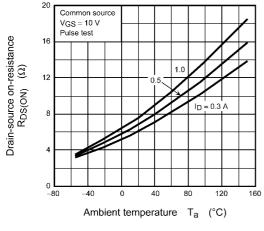


Fig. 8.7 R_{DS(ON)} - T_a

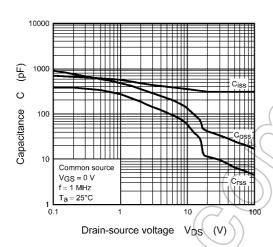


Fig. 8.9 C - V_{DS}

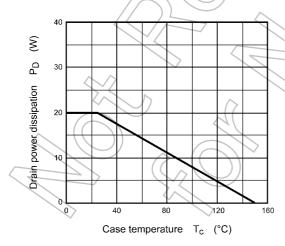


Fig. 8.11 P_D - T_c (Guaranteed Maximum)

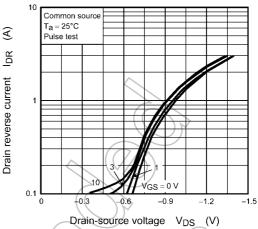
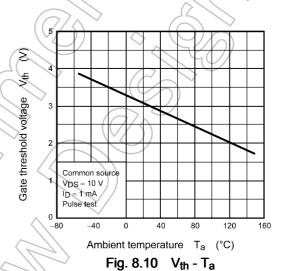


Fig. 8.8 I_{DR} - V_{DS}



SON VDS 16 16 SS NO VDD = 100 V 12 BELON DOS -LIE 1 A Ta = 25°C Pulse test DO NOS - LIE 1 A Ta = 25°C Pulse

 $\label{eq:charge_Qg} \mbox{Total gate charge} \quad \mbox{Q_g} \quad \mbox{(nC)} \\ \mbox{Fig. 8.12} \quad \mbox{Dynamic Input/Output Characteristics} \\$

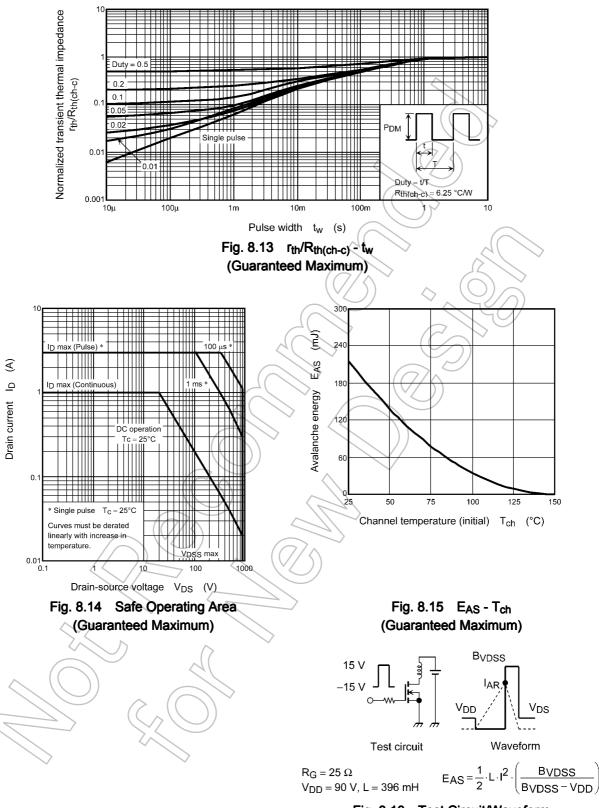


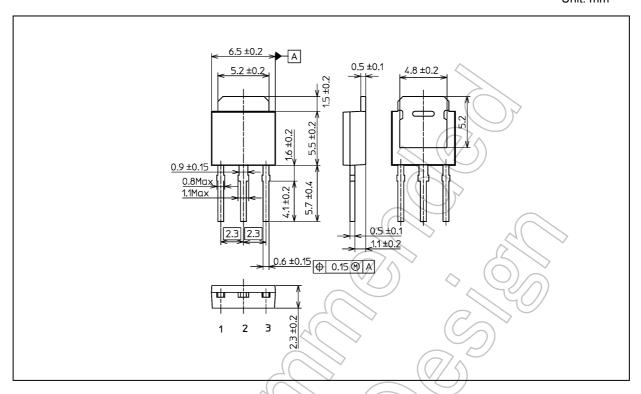
Fig. 8.16 Test Circuit/Waveform

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

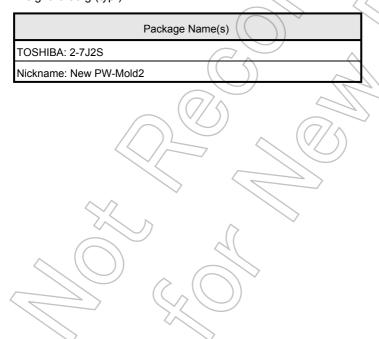


Package Dimensions

Unit: mm



Weight: 0.36 g (typ.)





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